

**PRELIMINARY**  
Notice: This is not a final specification.  
Some parametric limits are subject to change.

MITSUBISHI SEMICONDUCTOR<Digi./Ana. INTERFACE>

**M62216FP**

Low Voltage Operation STEP-UP DC-DC Converter

## GENERAL DESCRIPTION

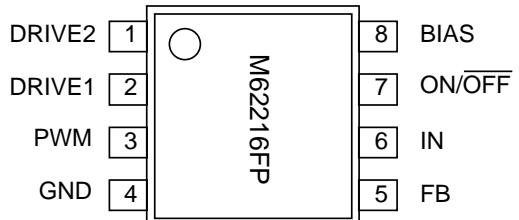
The M62216FP is designed as a low voltage operation STEP-UP DC-DC converter.

This IC can be operated at very low input voltage (min. 0.9V) and low power dissipation (a circuit current is less than 900 $\mu$ A). So, this IC is suitable for the power supply of portable systems that use low voltage batteries (DRY battery, rechargeable battery).

## FEATURES

- Pre-drive type PWM output (for pre-drive only)
- Low voltage operation •••••••••• VIN = 0.9V min
- Low power dissipation ••••••••• IB = 900 $\mu$ A typ
- Adjustable Pre-drive output current
- Built-in ON/OFF function •••••••• IB(OFF) = 25 $\mu$ A typ
- Applicable for STEP-DOWN converter

### PIN CONFIGURATION(TOP VIEW)

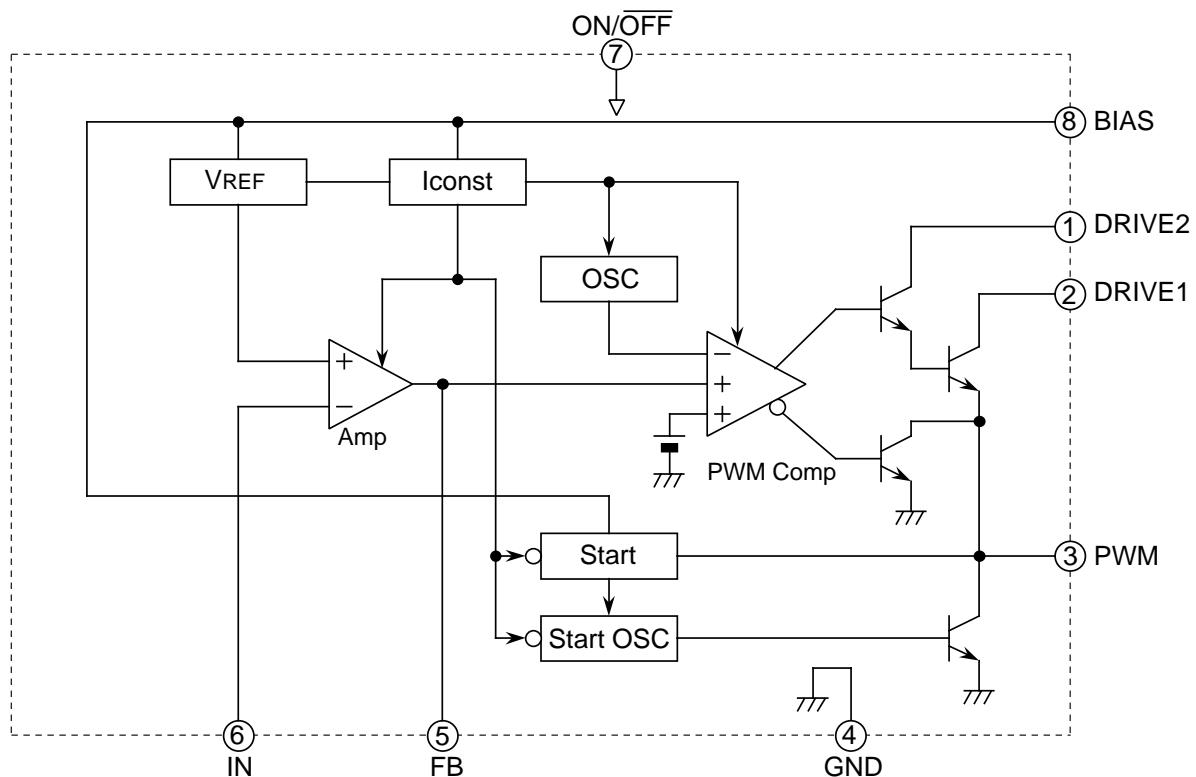


OUTLINE: 8P2S-A

## APPLICATION

DC-DC Converter for battery-powered portable systems

### BLOCK DIAGRAM



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**ABSOLUTE MAXIMUM RATINGS (Ta=25°C , unless otherwise noted)**

Symbol	Parameter	Condition	Ratings	Unit
VIN	Input Voltage		15.5	V
VBIAS	Bias Terminal Supply Voltage		15.5	V
VDRIVE1	Drive1 Terminal Supply Voltage		15.5	V
VDRIVE2	Drive2 Terminal Supply Voltage		15.5	V
IDRIVE1	Drive1 Terminal Input Voltage		100	mA
IDRIVE2	Drive2 Terminal Input Voltage		10	mA
Pd	Power Dissipation	Ta = 25°C	440	mW
Topr	Operating Temperature		-20 to +85	°C
Tstg	Storage Temperature		-40 to +150	°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C, VIN=1.7V, VOUT = VBIAS= 3.0V, unless otherwise noted)**

Block	Symbol	Parameter	Test Condition	Limits			Unit
				Min.	Typ.	Max.	
All Device	VIN	Input Voltage Range		0.9		15	V
	VBIAS	BIAS Voltage Setting Range		(1.7)		15	V
	IB	BIAS Current			900		μA
	IB(OFF)	BIAS Current at OFF Mode			25		μA
Voltage Reference	VREF	Reference Voltage		1.19	1.25	1.31	V
	VREF-I	Input Regulation of VREF			5		mV
	VREF-B	BIAS Voltage Regulation of VREF	VBIAS=1.7~15V		5		mV
Error Amp.	IIN	Input Current			20		nA
	AV	Open Loop Voltage Gain			80		dB
	IFB+	FB Terminal Sink Current			900		μA
	IFB-	FB Terminal Source Current			50		μA
Osc.	fosc	Oscillation Frequency			100		kHz
OUTPUT	Vsat1	Saturation Voltage between PWM Term. and DRIVE1 Term.	IDRIVE1=50mA, IDRIVE2=5mA		0.3		V
	Vsat2	Saturation Voltage between PWM Term. and DRIVE2 Term.			1.0		V
	IL1	Leak Current of DRIVE1 Terminal				1	μA
	IL2	Leak Current of DRIVE2 Terminal				1	μA
	VPWM(L)	Output Low Voltage of PWM Terminal	IPWM=1mA		0.3		V
ON/OFF	ION	Input Current of ON/OFF Terminal At ON Status			2		μA
	VTH(ON)	Threshold Voltage of ON/OFF Terminal			0.7		V

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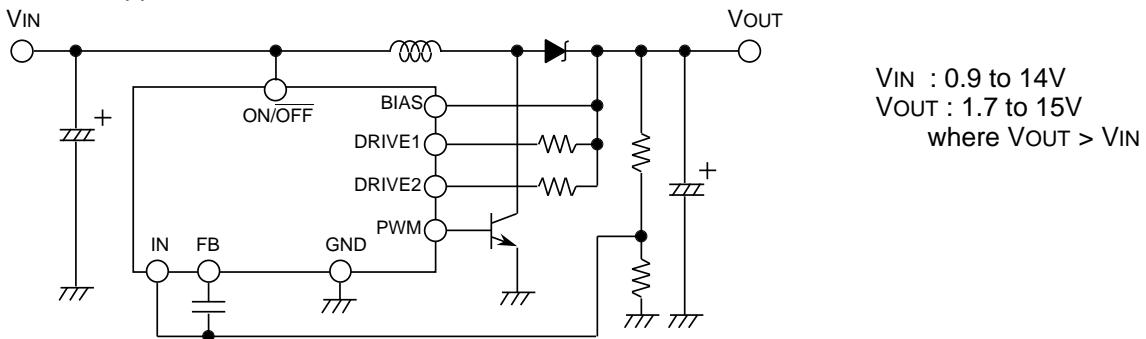
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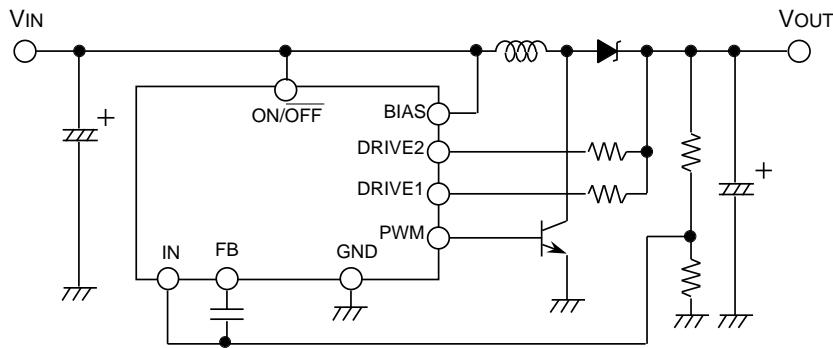
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## Application Example

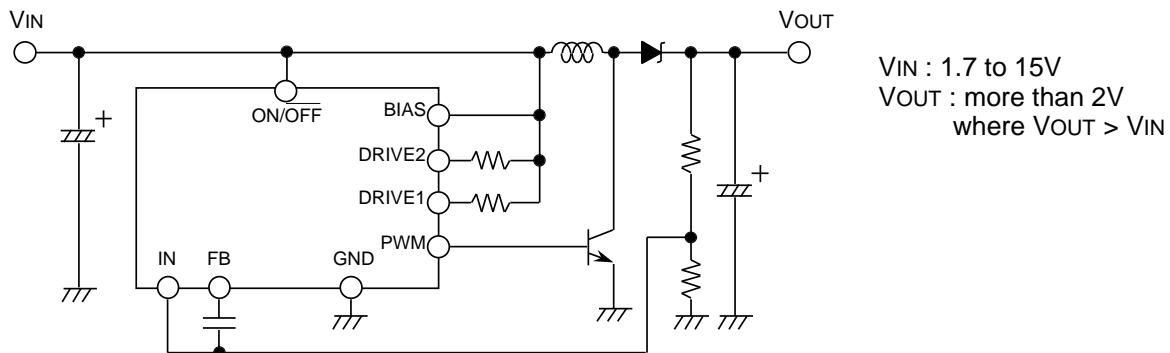
### (1). Standard Application circuit



### (2). Application circuit 1 (VIN = 1.7V)



### (3). Application circuit 2 (VOUT > 15V)



### (4). Application circuit for STEP-DOWN Circuit

